







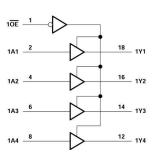
SN74AHCT244Q

SGDS024A - FEBRUARY 2002 - REVISED MAY 2023

SN74AHCT244Q Octal Buffer/driver with 3-State Outputs

1 Features

- Q devices meet automotive performance requirements
- Customer-specific configuration control can be supported along with major-change approval
- EPIC™ (Enhanced-Performance Implanted CMOS) process
- Inputs are TTL-Voltage compatible Latch-Up performance exceeds 250 mA per JESD 17



2 Description

This octal buffer/driver is designed specifically to improve both the performance and density of 3state memory-address drivers, clock drivers, and busoriented receivers and transmitters.

Package Information

PART NUMBER	PACKAGE ¹	BODY SIZE (NOM)				
SN74AHCT244Q	DW (SOIC, 20)	12.80 mm × 7.50 mm				
SIV/4ALICT244Q	PW (TSSOP, 20)	6.5 mm × 4.4 mm				

1. For all available packages, see the orderable addendum at the end of the data sheet.

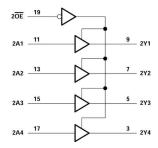




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3 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Revision * (February 2002) to Revision A (May 2023)	Page
•	Added Package Information table, Pin Functions table, and Thermal Information table	1



4 Pin Configuration and Functions

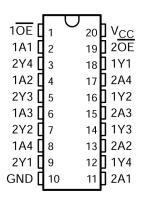


Figure 4-1. DW or PW Package (Top View)

Pin Functions

PIN			PERCENTION		
Name NO.		I/O1	DESCRIPTION		
1 OE	1	I	Bank 1, output enable, active low		
1A1	2	I	Bank 1, channel 1 input		
2Y4	3	0	Bank 2, channel 4 output		
1A2	4	I	Bank 1, channel 2 input		
2Y3	5	0	Bank 2, channel 3 output		
1A3	6	I	Bank 1, channel 3 input		
2Y2	7	0	Bank 2, channel 2 output		
1A4	8	I	Bank 1, channel 4 input		
2Y1	9	0	Bank 2, channel 1 output		
GND	10	_	Ground		
2A1	11	I	Bank 2, channel 1 input		
1Y4	12	0	Bank 1, channel 4 output		
2A2	13	I	Bank 2, channel 2 input		
1Y3	14	0	Bank 1, channel 3 output		
2A3	15	I	Bank 2, channel 3 input		
1Y2	16	0	Bank 1, channel 2 output		
2A4	17	I	Bank 2, channel 4 input		
1Y1	18	0	Bank 1, channel 1 output		
2 OE	19	I	Bank 2, output enable, active low		
V _{CC}	20	_	Positive supply		



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	C Supply voltage range		-0.5	7	V
V _I (¹)	Input voltage range		-0.5	7	V
V _O (¹)	Output voltage range		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	(V _I < 0)		-20	mA
I _{OK}	Output clamp current	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
Io	Continuous output current	$(V_O = 0 \text{ to } V_{CC})$		±25	mA
	Continuous current through V _{CC} or GND			±75	mA
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions

(see Note 1)

		MIN	MAX	UNIT
V _{CC}	Supply voltage	4.5	5.5	V
V _{IH}	High-level input voltage	2		V
V _{IL}	Low-level input voltage		0.8	V
VI	Input voltage	0	5.5	V
Vo	Output voltage	0	V _{CC}	V
I _{OH}	High-level output current		-8	mA
I _{OL}	Low-level output current		8	mA
T _A	Operating free-air temperature	-40	125	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

5.3 Thermal Information

		SN74AHCT2		
THERMAL METRIC(1)		DW (SOIC)	PW (TSSOP)	UNIT
		20 PINS	20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	58	83	°C/W

(1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	,	V	T _A = 25°C			MIN MA	MAY	UNIT
PARAMETER	TEST CONDITIONS		V _{cc}	MIN	TYP	MAX	IVIIN	MAX	UNII
V	I _{OH} = -50 μA		I.5 V	4.4	4.5		4.4		V
V_{OH}	I _{OH} = -8 mA		1.5 V	3.94			3.8		V
V	I _{OL} = 50 μA		I.5 V			0.1		0.1	V
V _{OL}	I _{OL} = 8 mA		1.5 V	0.36			0.44	V	
I _{OZ}	V _o = V _{CC} or GND	Ę	5.5 V			±0.25		±2.5	μA
I _I	V _I = 5.5 V or GND	0 V	′ to 5.5 V			±0.1		±1	μΑ
I _{CC}	$V_I = V_{CC}$ or GND, $I_O =$	= 0 5	5.5 V			4		40	μΑ
ΔI _{CC} (1)	One input at 3.4 V, Other inputs at V _{CC} or GND	Ę	5.5 V			1.35		1.5	mA
C _i	V _I = V _{CC} or GND		5 V		2.5	10			pF
Co	Vo = V _{CC} or gnd		5 V		3				pF

⁽¹⁾ This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

5.5 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 6-1)

PARAMETER	FROM (INPUT)	(INPUT) TO (OUTPUT) LOAD CAPACI		T _A = 25°C			MIN MAX	UNIT	
PARAMETER	FROW (INFOT)	10 (001701)	LOAD CAPACITANCE	MIN	TYP	MAX	IVIIIN	IVIAA	UNII
t _{PLH}	۸	Y	C _L = 15 pF		5.4	7.4	1	8.5	no
t _{PHL}	A	ť	C _L = 15 pr		5.4	7.4	1	8.5	ns
t _{PZH}	- ŌE Y	V	C _L = 15 pF		7.7	10.4	1	12	no
t _{PZL}		ť	C _L = 15 pr		7.7	10.4	1	12	ns
t _{PHZ}	- ŌĒ	Y	C = 15 pF		5	9.4	1	10	20
t _{PLZ}		ť	C _L = 15 pF		5	9.4	1	10	ns
t _{PLH}	- A	Y	C = 50 pF		5.9	8.4	1	9.5	20
t _{PHL}		ť	C _L = 50 pF		5.9	8.4	1	9.5	ns
t _{PZH}	ŌĒ	Y	C _L = 50 pF		8.2	11.4	1	13	20
t _{PZL}	OE .	ī	C _L = 50 pr		8.2	11.4	1	13	ns
t _{PHZ}	- OE	V	C = 50 pF		8.8	11.4	1	13	20
t _{PLZ}	J	r	Y $C_L = 50 \text{ pF}$		8.8	11.4	1	13	ns
t _{sk(o)}			C _L = 50 pF			1			ns



5.6 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C (see }^{\text{Note 1}})$

	PARAMETER	MIN	TYP	MAX	UNIT
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4.1		V
$V_{IH(D)}$	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V

⁽¹⁾ Characteristics are for surface-mount packages only.

5.7 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

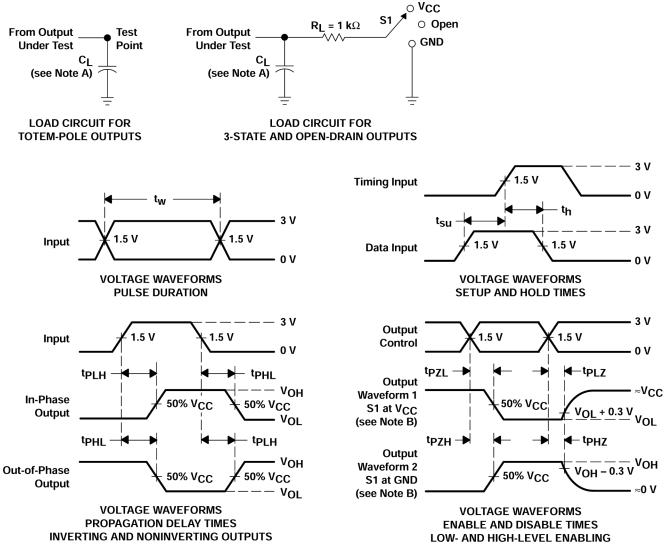
	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	No load, f = 1 MHz	8.2	pF

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6 Parameter Measurement Information



- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 3 ns, $t_f \leq$ 3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 6-1. Load Circuit and Voltage Waveforms

TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{CC}
t _{PHZ} /t _{PZH}	GND
Open Drain	V _{CC}



7 Detailed Description

7.1 Overview

The SN74AHCT244Q is organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

7.2 Functional Block Diagram

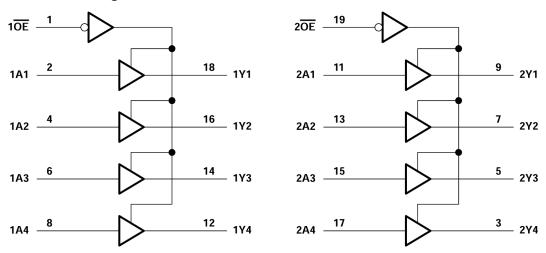


Figure 7-1. Logic Diagram (Positive Logic)

This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

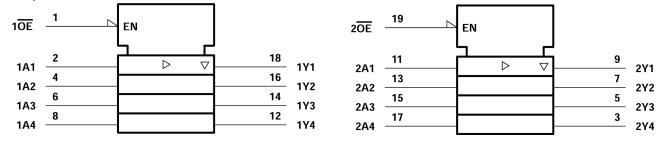


Figure 7-2. Logic Symbol

7.3 Device Functional Modes

Table 7-1. Function Table (Each 4-Bit Buffer/driver)

INPUTS	OUTPUT Y				
ŌĒ	Α	OUIFUL			
L	Н	Н			
L	L	L			
Н	Х	Z			

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74AHCT244QDWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT244Q	Samples
SN74AHCT244QPWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB244Q	Samples
SN74AHCT244QPWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		HB244Q	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT244QDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHCT244QPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHCT244QPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AHCT244QPWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

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*All dimensions are nominal

7 til dillionolono are memiliar							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT244QDWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHCT244QPWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74AHCT244QPWR	TSSOP	PW	20	2000	353.0	353.0	32.0
SN74AHCT244QPWRG4	TSSOP	PW	20	2000	356.0	356.0	35.0



SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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